

Vishay Siliconix

# P-Channel 20 V (D-S) 175 °C MOSFET

### **DESCRIPTION**

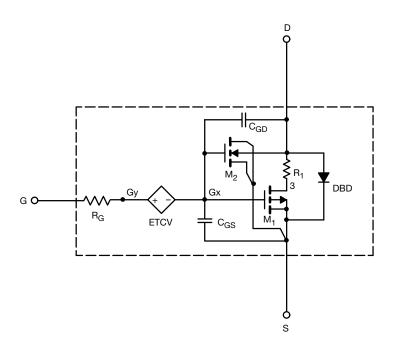
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the -  $55\,^{\circ}$ C to +  $125\,^{\circ}$ C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### **CHARACTERISTICS**

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- · Model the Gate Charge

### SUBCIRCUIT MODEL SCHEMATIC



### Note

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

# **SPICE Device Model SQ2301ES**

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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	0.5	-	V
Drain-Source On-State Resistancea	R <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, I_D = -2.8 \text{ A}$	0.08	0.08	Ω
		$V_{GS} = -2.5 \text{ V}, I_D = -2 \text{ A}$	0.11	0.11	
Forward Transconductance <sup>a</sup>	9fs	V <sub>DS</sub> = - 1.6 V, I <sub>D</sub> = - 2.8 A	6.4	7	S
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> = - 1.6 A	- 0.75	- 0.80	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = - 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	336	340	pF
Output Capacitance	C <sub>oss</sub>		79	80	
Reverse Transfer Capacitance	C <sub>rss</sub>		53	55	
Total Gate Charge <sup>c</sup>	$Q_g$		4	5	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -2.8 \text{ A}$	0.7	0.7	nC
Gate-Drain Charge <sup>c</sup>	$Q_{gd}$		1.3	1.3	

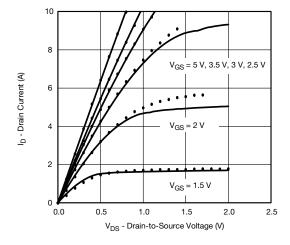
#### Notes

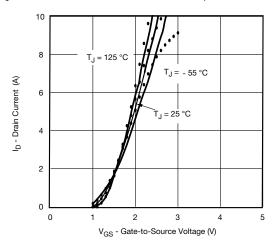
- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operting temperature.

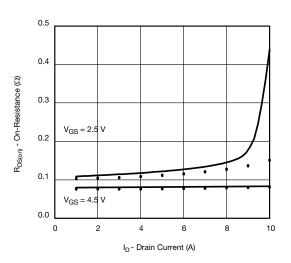
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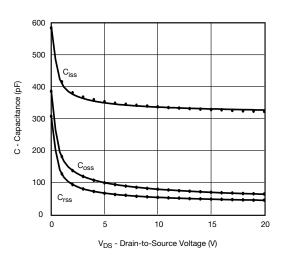
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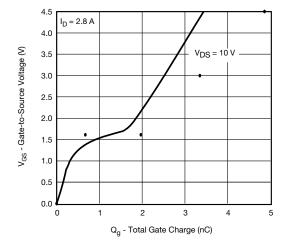
## **COMPARISON OF MODEL WITH MEASURED DATA** ( $T_J = 25 \, ^{\circ}\text{C}$ , unless otherwise noted)

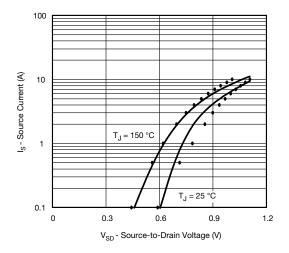












**Note**Dots and squares represent measured data.



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